



DMT10H072LFV

100V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
	$62m\Omega @ V_{GS} = 10V$	20A
100V	77mΩ @ V _{GS} = 6V	16A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

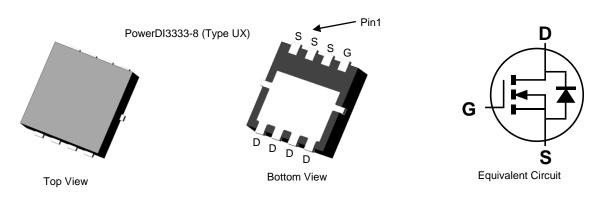
- **Power Management Functions**
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

Features and Benefits

- Low R_{DS(ON)} Ensures On State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher **Density End Products**
- Occupies just 33% of the Board Area Occupied by SO-8 **Enabling Smaller End Product**
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

	Part Number	Case	Quantity per Reel	
	DMT10H072LFV-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel	
DMT10H072LFV-13		PowerDI3333-8 (Type UX)	3,000/Tape & Reel	
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.				

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2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

4. For packaging details, go to our website athttps://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



T72= Product Type Marking Code YYWW = Date Code Marking \overline{YY} = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	100	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current, $V_{GS} = 10V$ (Note 5)	T _A = +25°C T _A = +70°C	ID	4.7 3.7	А
Continuous Drain Current $V_{GS} = 10V$ (Note 6)	T _C = +25°C T _C = +70°C	ID	20 16	А
Pulsed Drain Current (10µs Pulse, T _C =+25°C, Package Limited)	I _{DM}	80	А	
Pulsed Body Diode Current (10µs Pulse, T _C =+25°C, Package Lim	I _{SM}	80	А	
Maximum Body Diode Continuous Current	ls	2	А	
Avalanche Current (Note 9), L=0.1mH	I _{AS}	6	А	
Avalanche Energy (Note 9), L=0.1mH	E _{AS}	1.8	mJ	

Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	2	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{eJA}	61	°C/W
Total Power Dissipation (Note 6)	PD	37.8	W
Thermal Resistance, Junction to Case (Note 6)	R _{eJC}	3.3	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	.		- 71-				
Drain-Source Breakdown Voltage	BV _{DSS}	100	-	-	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	-	-	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1.5	-	2.8	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		-	50.6	62	mΩ	$V_{GS} = 10V, I_D = 4.5A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	-	61.2	77	11122	$V_{GS} = 6V, I_D = 4A$	
	R _{DS(ON)}	-	82.5	109	mΩ	V _{GS} = 4.5V, I _D = 2.7A	
Diode Forward Voltage	V _{SD}	-	0.76	1	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 8)						*	
Input Capacitance	C _{iss}	-	228	-	pF	− V _{DS} = 50V, V _{GS} = 0V, − f = 1MHz	
Output Capacitance	Coss	-	89.3	-	pF		
Reverse Transfer Capacitance	C _{rss}	-	2.5	-	pF		
Gate Resistance	Rg	-	8.2	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	2.5	-	nC		
Total Gate Charge (V _{GS} = 10V)	Qq	-	4.5	-	nC	7.,,	
Gate-Source Charge	Q _{gs}	-	0.6	-	nC	$V_{DS} = 50V, I_D = 4.5A$	
Gate-Drain Charge	Q _{gd}	-	1.3	-	nC	7	
Turn-On Delay Time	t _{D(ON)}	-	3.0	-	ns		
Turn-On Rise Time	t _R	-	3.1	-	ns	$V_{DS} = 50V, R_L = 11\Omega$ $V_{GS} = 10V, R_{GEN} = 3\Omega$	
Turn-Off Delay Time	t _{D(OFF)}	-	12.3	-	ns		
Turn-Off Fall Time	tF	-	4.3	-	ns		
Reverse Recovery Time	t _{RR}	-	22.9	-	ns		
Reverse Recovery Charge	Q _{RR}	-	45.2	-	nC	I _F = 4.5A, di/dt = 300A/μs	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

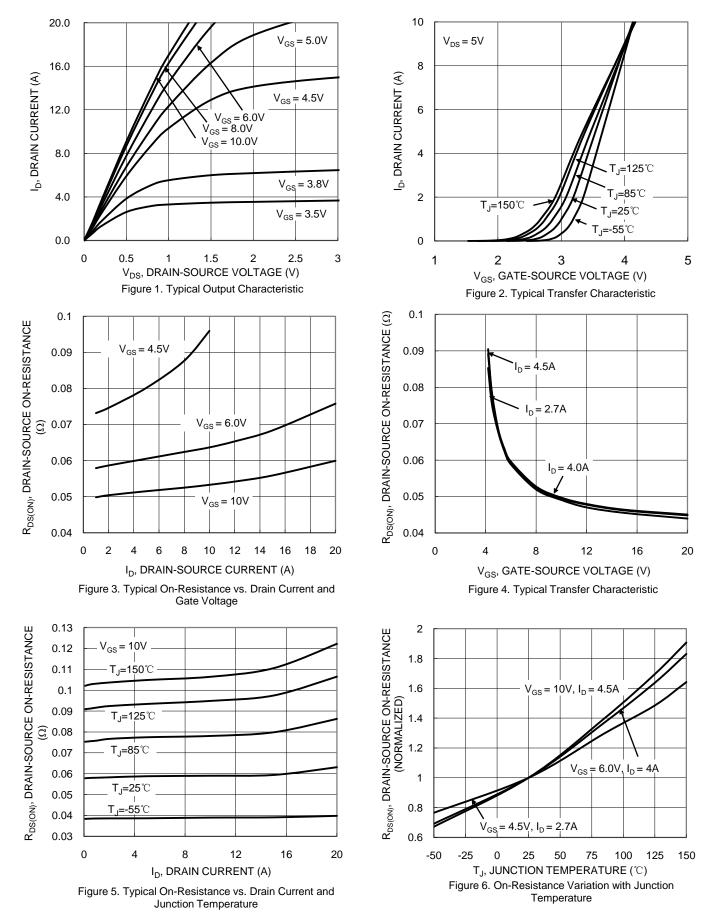
6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing. 9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

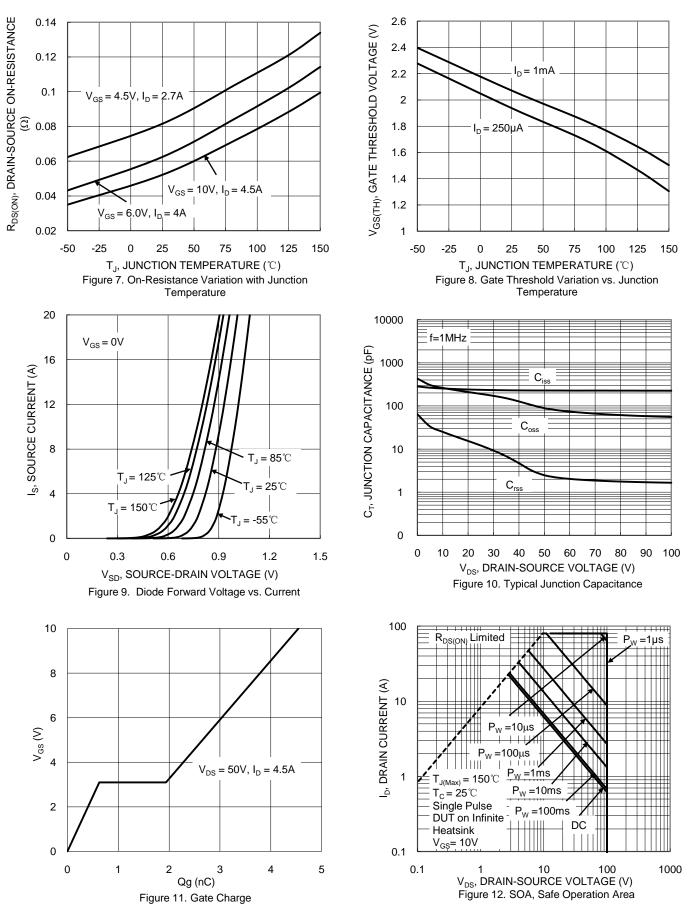


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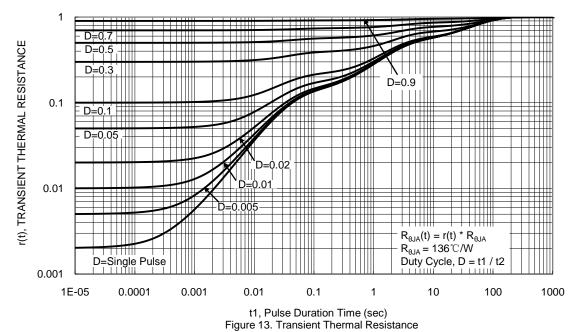


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DMT10H072LFV Datasheet number: DS40030 Rev. 5 - 2



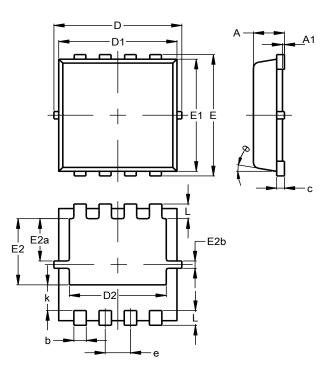




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)

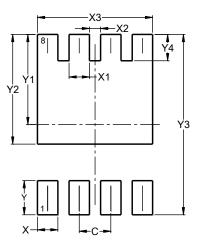


PowerDI3333-8					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
ш	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E2a	0.95	1.35	1.15		
E2b	0.10	0.30	0.20		
е	0	0.65 BSC			
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
X3	2.370		
Y	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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